

M/A-COM Products

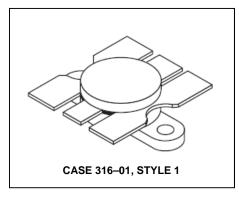
Released - Rev. 07.07

## The RF Line NPN Silicon Power Transistor 100W, 30-200MHz, 28V

Designed primarily for wideband large-signal output amplifier stages in 30-200 MHz frequency range.

- Guaranteed performance at 150 MHz, 28 Vdc Output power = 100 W Minimum gain = 9.0 dB
- Built-in matching network for broadband operation
- 100% tested for load mismatch at all phase angles with 30:1 VSWR
- Gold metallization system for high reliability
- High output saturation power ideally suited for 30 W carrier/120 W
- Peak AM amplifier service
- Guaranteed performance in broadband test fixture

### Product Image



#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V <sub>CEO</sub>	35	Vdc
Collector–Base Voltage	V <sub>CBO</sub>	65	Vdc
Emitter–Base Voltage	V <sub>EBO</sub>	4.0	Vdc
Collector Current — Continuous — Peak (10 seconds)	IC	12 18	Adc
Total Device Dissipation @ T <sub>C</sub> = 25°C (1) Derate above 25°C	PD	270 1.54	Watts W/∘C
Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°C

#### THERMAL CHARACTERISTICS

Characteristic		Symbol	Max		Unit
Thermal Resistance, Junction to Case		R <sub>θJC</sub>	0.65		°C/W
ELECTRICAL CHARACTERISTICS (T <sub>C</sub> = 25°C unless otherwise noted.)					
Characteristic	Symbol	Min	Typ	Max	Unit

be

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Collector–Emitter Breakdown Voltage (I <sub>C</sub> = 100 mAdc, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	35	_	_	Vdc
Collector–Emitter Breakdown Voltage (I <sub>C</sub> = 100 mAdc, V <sub>BE</sub> = 0)	V <sub>(BR)CES</sub>	65	_	_	Vdc
Collector–Base Breakdown Voltage (I <sub>C</sub> = 100 mAdc, I <sub>E</sub> = 0)	V <sub>(BR)CBO</sub>	65	_	_	Vdc
Emitter–Base Breakdown Voltage (I <sub>E</sub> = 10 mAdc, I <sub>C</sub> = 0)	V <sub>(BR)EBO</sub>	4.0	_	_	Vdc
Collector Cutoff Current (V <sub>CB</sub> = 30 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>	_	—	5.0	mAdc
ON CHARACTERISTICS					
DC Current Gain (I <sub>C</sub> = 5.0 Adc, V <sub>CE</sub> = 5.0 Vdc)	h <sub>FE</sub>	10	25	80	_

#### NOTE:

(continued)

1. This device is designed for RF operation. The total device dissipation rating applies only when the device is operated as an RF amplifier.

### ELECTRICAL CHARACTERISTICS - continued (T<sub>C</sub> = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
DYNAMIC CHARACTERISTICS					
Output Capacitance (V <sub>CB</sub> = 28 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>ob</sub>	_	150	175	pF
FUNCTIONAL TESTS (Figure 2)					
Common–Emitter Amplifier Power Gain (V <sub>CC</sub> = 28 Vdc, P <sub>out</sub> = 100 W, f = 150 MHz, I <sub>C</sub> (Max) = 6.5 Adc)	G <sub>PE</sub>	9.0	10	_	dB
Collector Efficiency (V <sub>CC</sub> = 28 Vdc, P <sub>out</sub> = 100 W, f = 150 MHz, I <sub>C</sub> (Max) = 6.5 Adc)	η	55	60	_	%
Load Mismatch (V <sub>CC</sub> = 28 Vdc, P <sub>out</sub> = 100 W CW, f = 150 MHz, VSWR = 30:1 all phase angles)	Ψ	No Degradation in Output Power			

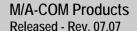
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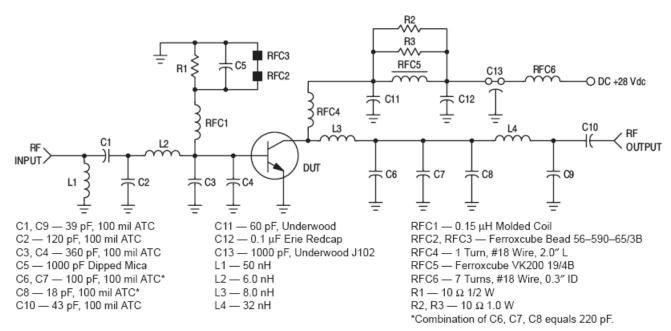
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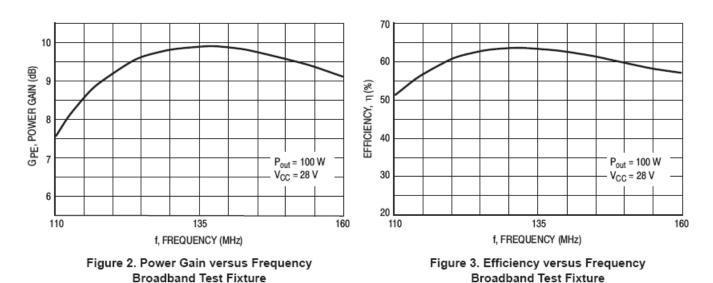


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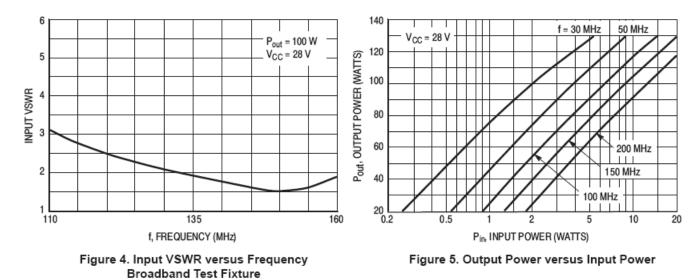
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### TYPICAL PERFORMANCE CURVES

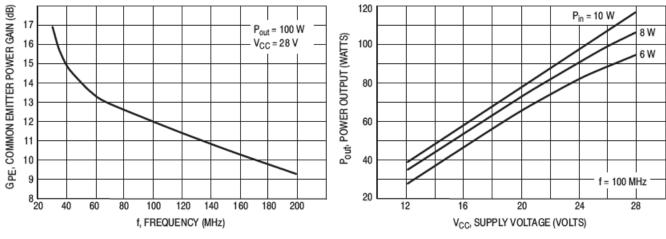
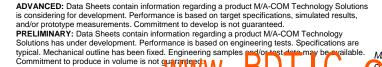


Figure 6. Power Gain versus Frequency

Figure 7. Power Output versus Supply Voltage



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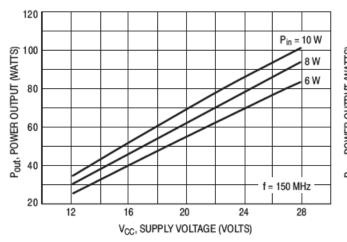
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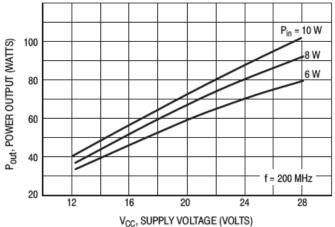
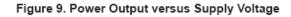
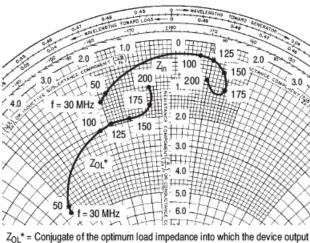


Figure 8. Power Output versus Supply Voltage





$V_{CC}$ = 28 V, $P_{out}$ = 100 W			
f MHz	Z <sub>in</sub> OHMS	Z <sub>OL</sub> * OHMS	
30	1.2 - j2.0	4.3 – j5.0	
50	1.0 – j1.8	4.0 – j4.9	
100	0.3 + j0.7	2.0 - j2.3	
125	0.3 + j1.0	1.9 – j1.9	
150	0.6 + j1.3	1.9 - j1.3	
175	1.0 + j1.5	1.6 - j0.6	
200	0.9 + j1.0	1.1 - j0.6	

Z<sub>OL</sub>\* = Conjugate of the optimum load impedance into which the device output operates at a given output power, voltage and frequency.

Figure 10. Series Equivalent Input-Output Impedance

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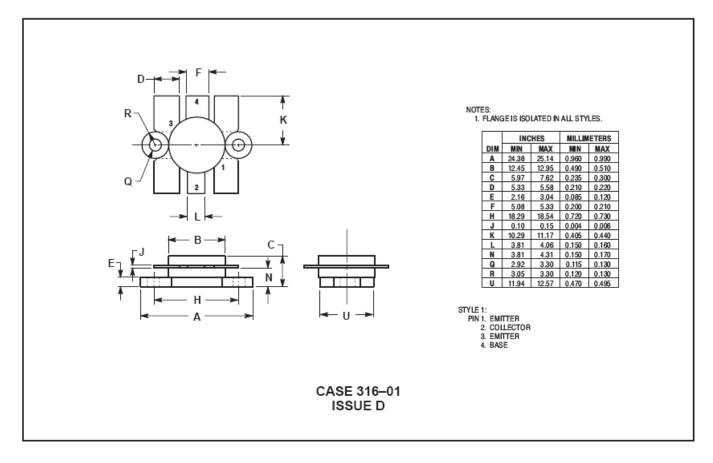
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